

EMI – the undesirable Effect of modern Power Electronics

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Agenda

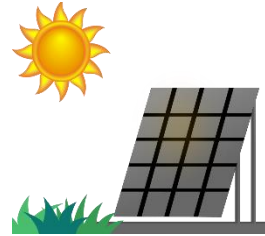
- **Introduction – Trends & Markets**
- **Power Electronics Basic Intro**
- **EMI from Power Electronics**
- **How modern Semiconductors change EMI behavior**
- **Who we are and What we offer**

Trends & Markets

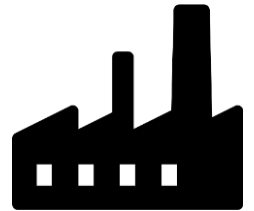
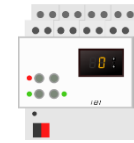
- Digitization – Smart X



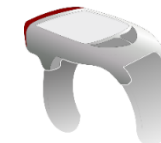
- Renewable Energy



- Electrification of Transportation



- Autonomous Driving



Why Power Electronics is now popular?

- **Digitization**

- Continuously growing Number of Battery Powered Devices
- IoT & **Autonomous Driving** → More Data → Growing # of Data Centers
- Growing need for electric Power

- **Electrification**

- Fast increasing number of Power Converters
- Growing need for electric Power
- Push extension of **Renewable Power** Generation

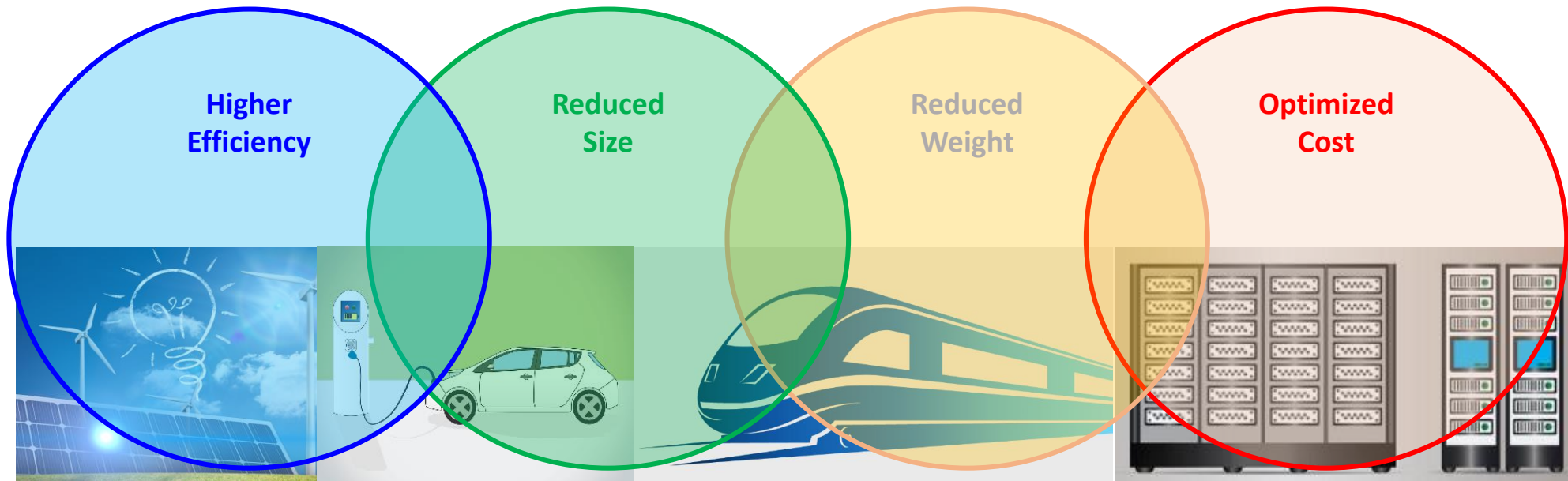
This all create the requirements for
Efficient, **High-Performance** and **Compliant**
Power Supplies



How achieve higher Efficiency?

WBG Semiconductors (SiC / GaN) can help to achieve the targets, because

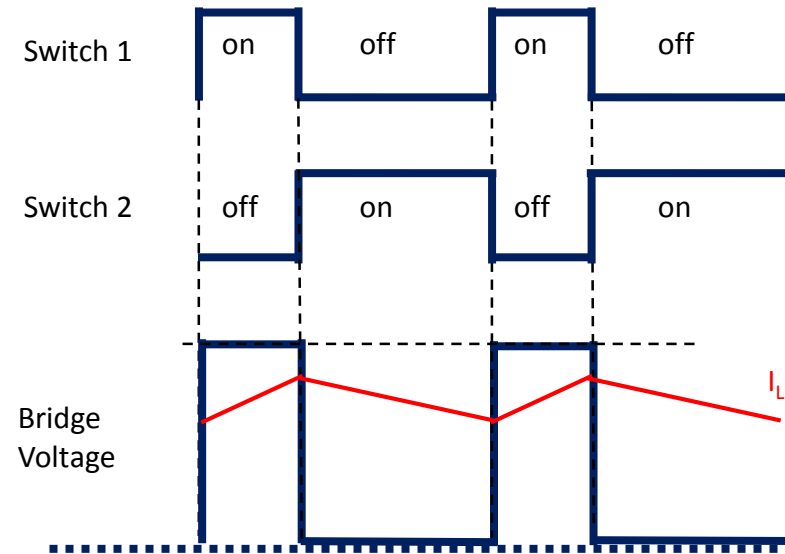
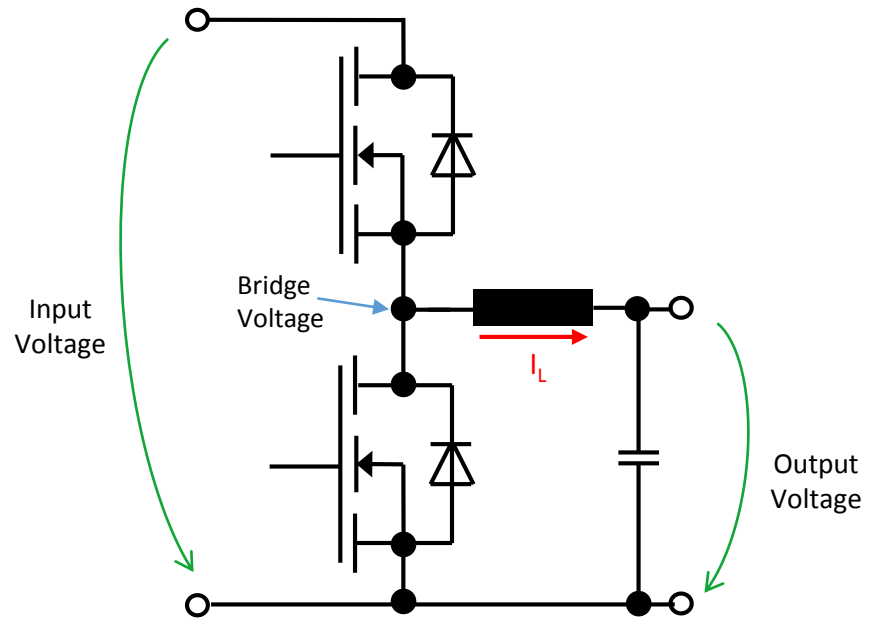
- Enable higher Switching Frequencies -> smaller periphere components
- Have 3x lower Switching Losses -> more efficient -> smaller heat sinks
- Provide 4x higher Power Density -> lower space requirement



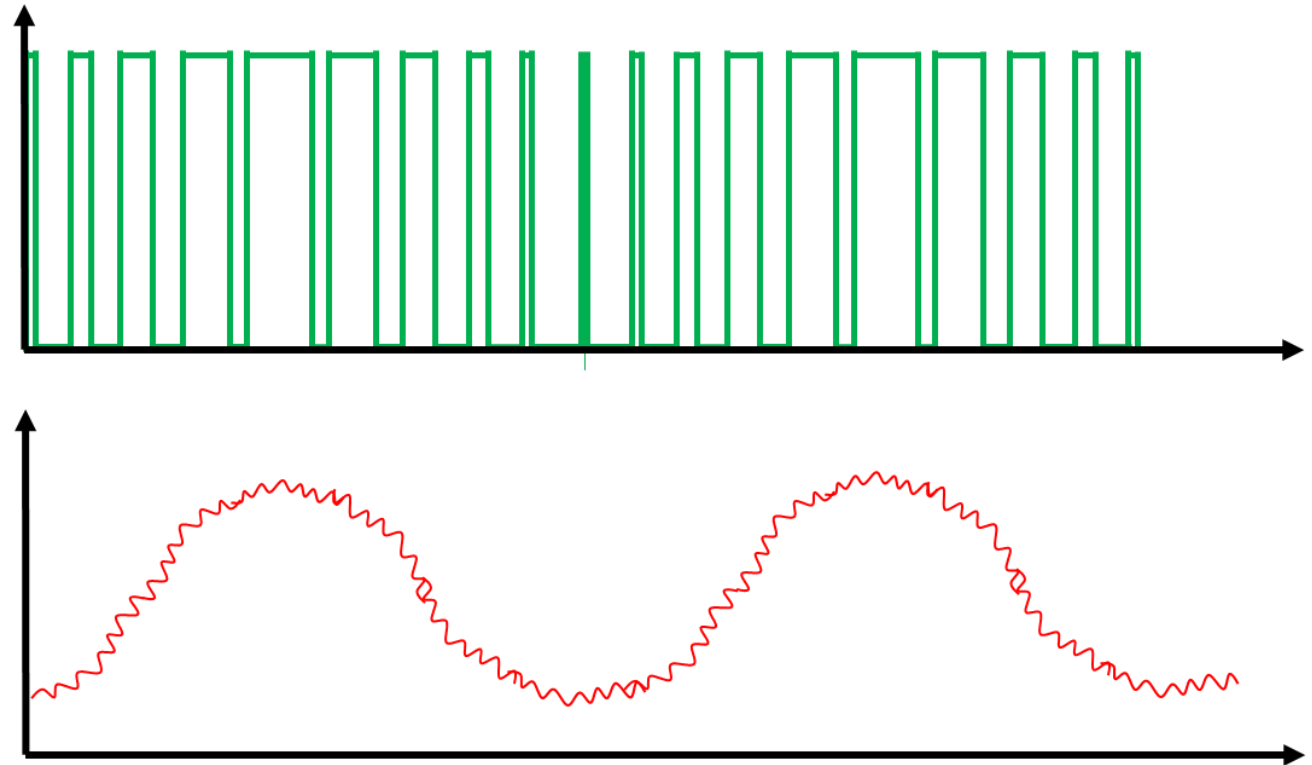
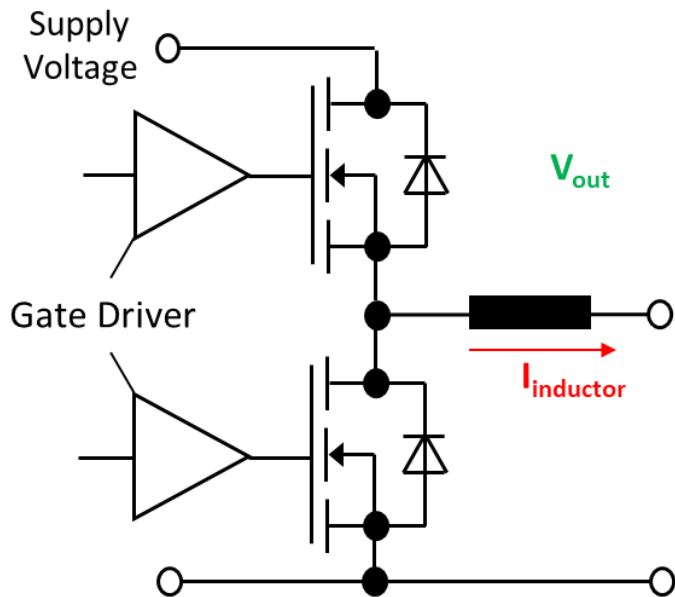
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Power Electronics Basics Intro



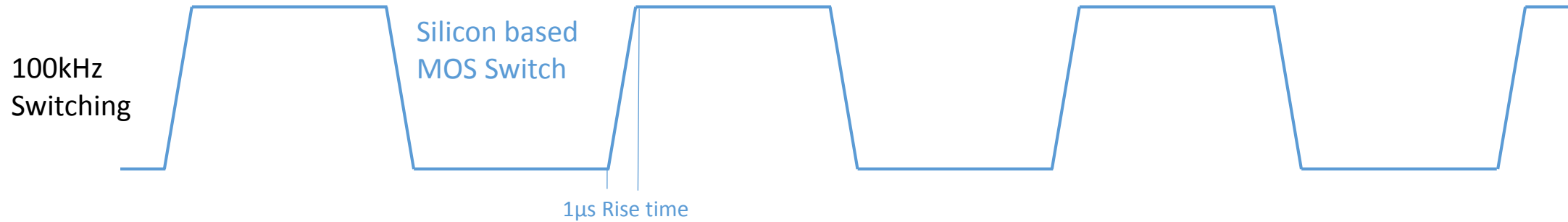
PWM Controlled Motor Drive



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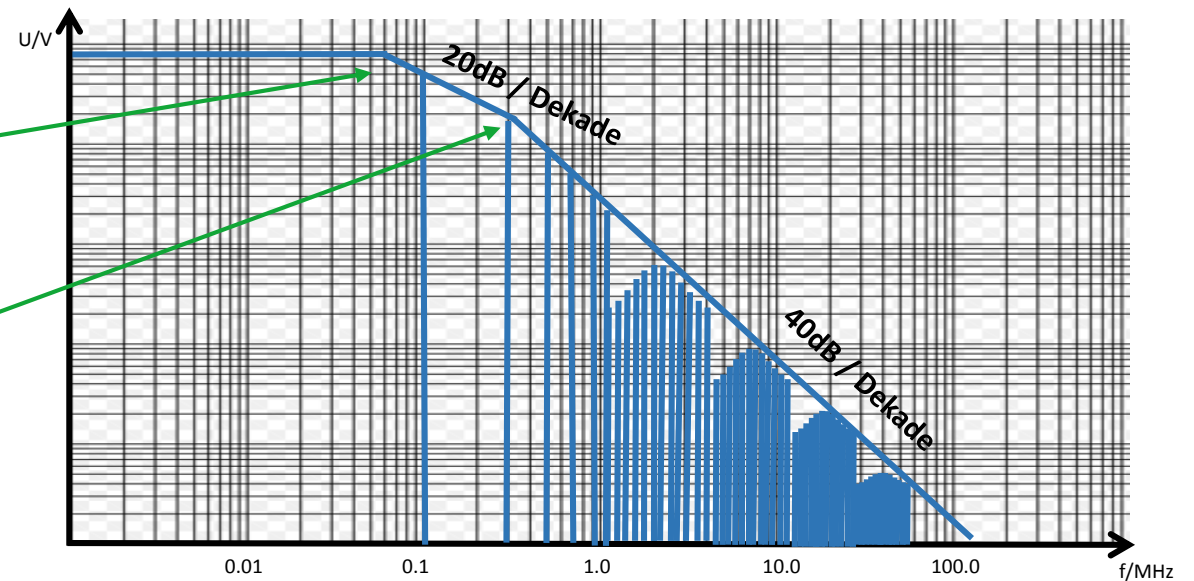
Frequency Consideration



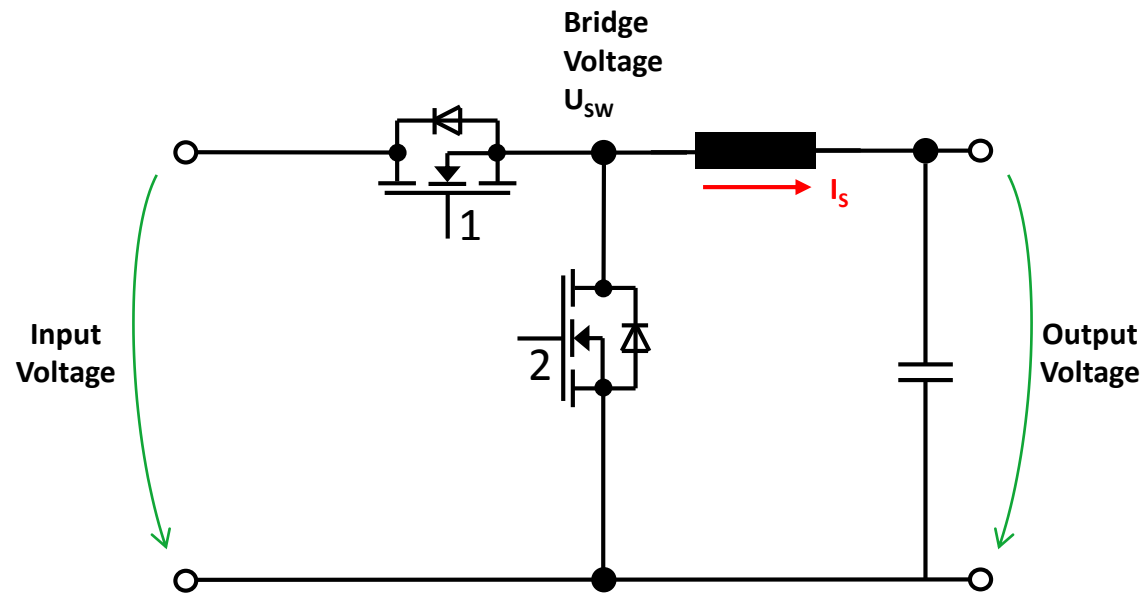
- 1st Frequency point = $\frac{2 * f_{sw}}{\pi}$
 (here = 63.7kHz)

- 2nd Frequency point = $\frac{1}{\pi * RiseTime}$

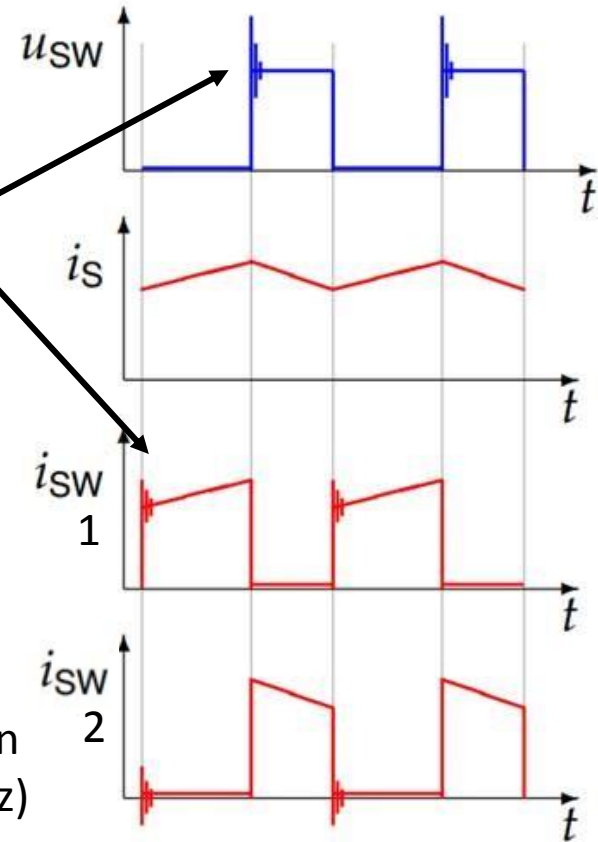
1µs Rise Time => 318,3kHz



Frequency Consideration



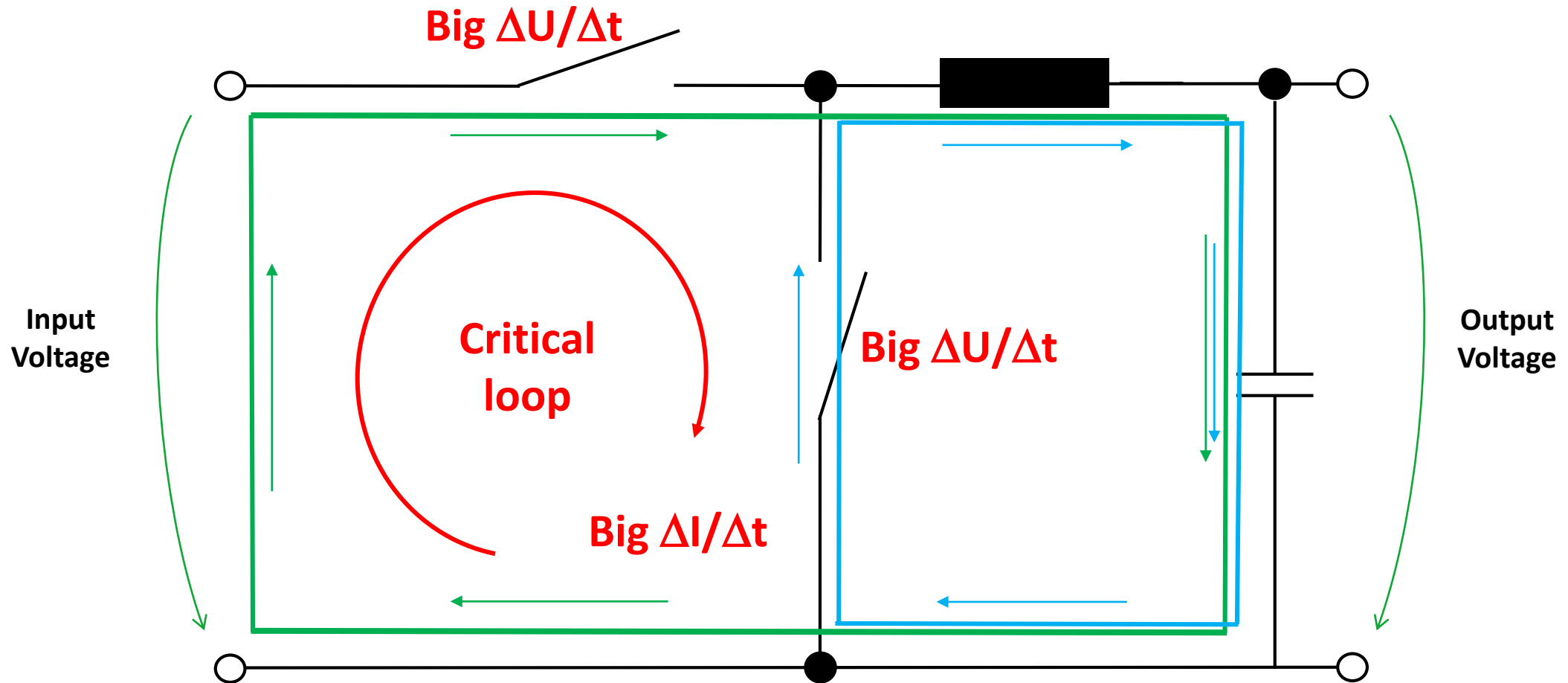
Source of Ringing:
LC resonance
circuit
e.g. C_{DS} / L_{trace}



Ringing Frequencies can be fairly high (>200MHz)

Partly property of
EMV-Wissen.de

Voltage / Current Consideration



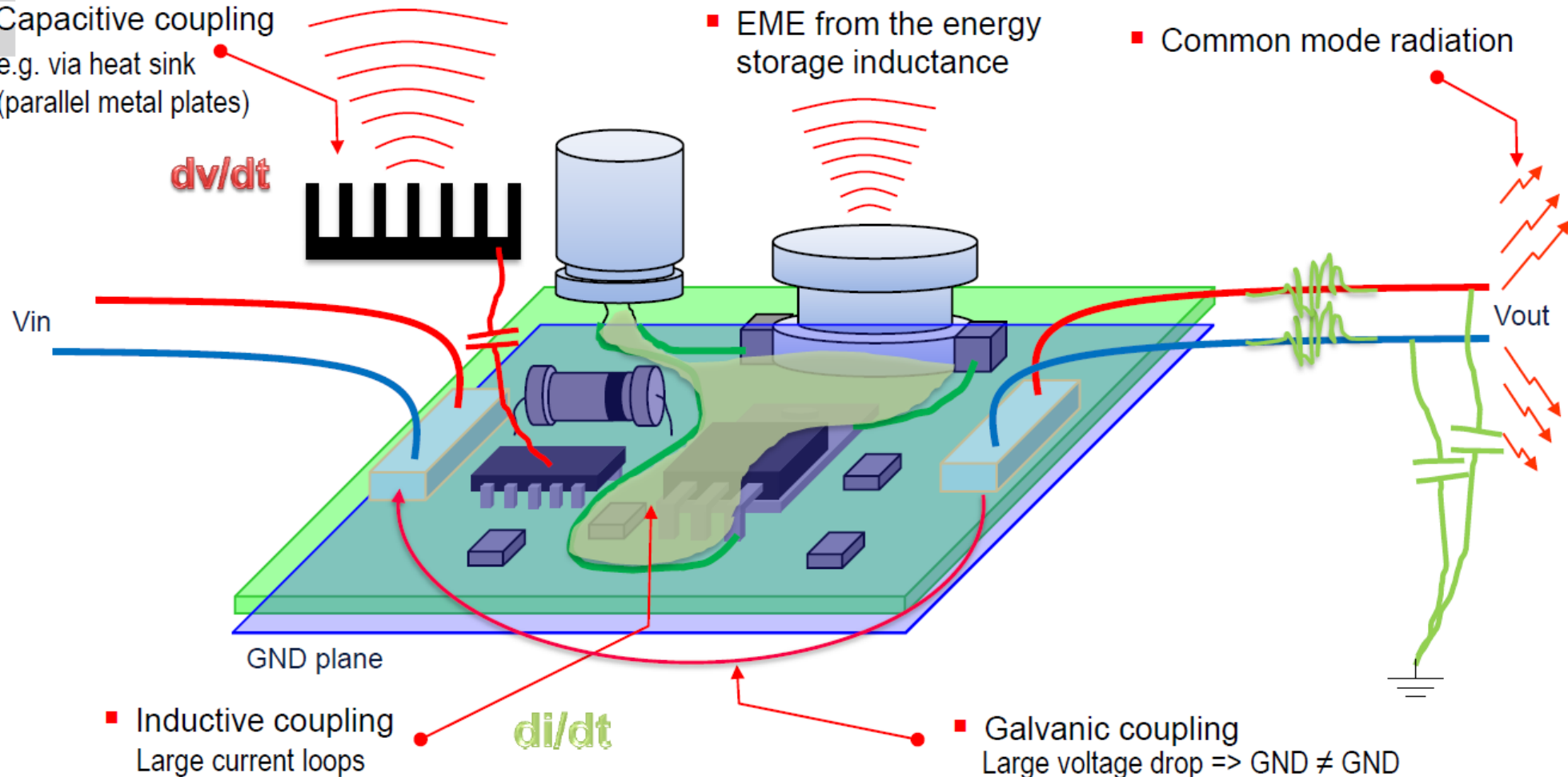
EM Emission Sources

- Capacitive coupling
e.g. via heat sink
(parallel metal plates)

dv/dt

- EME from the energy storage inductance

- Common mode radiation



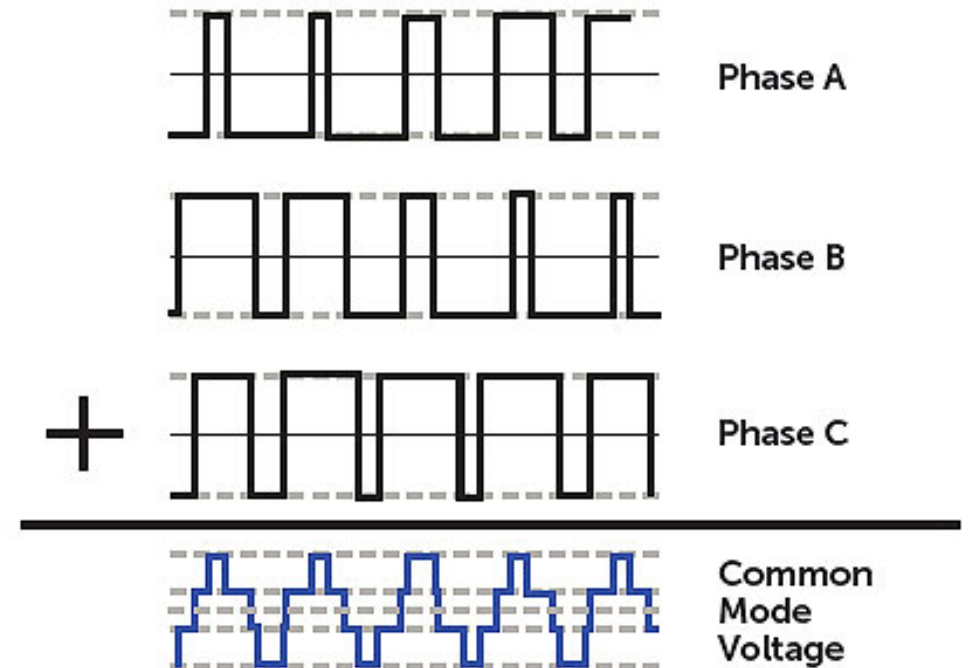
- Inductive coupling
Large current loops

di/dt

- Galvanic coupling
Large voltage drop => GND ≠ GND

Common Mode voltage

- Existing stray Capacities between Load And earth may result in common mode Currents
- Higher Switching Frequencies tend to produce more common mode voltage and current



This diagram shows the three-phase voltage waveforms in a typical PWM drive.

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“Classical” vs. “Modern” Semiconductors

- Higher Breakdown voltages -> higher switched voltage
→ Higher $\Delta U/\Delta t$ → critical Capacitive coupling
- Lower ON-Resistance -> higher currents possible
→ Higher $\Delta I/\Delta t$ → critical Inductive Coupling
- Faster Switching
- Steeper Edges

Effect of steeper Edges

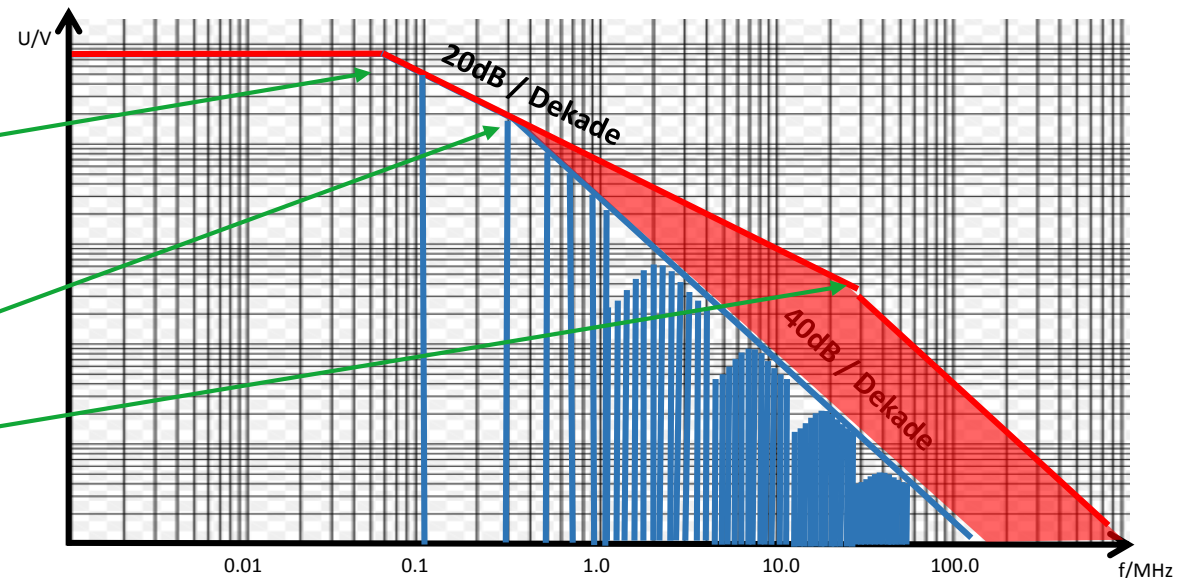


- 1st Frequency point = $\frac{2 * f_{sw}}{\pi}$
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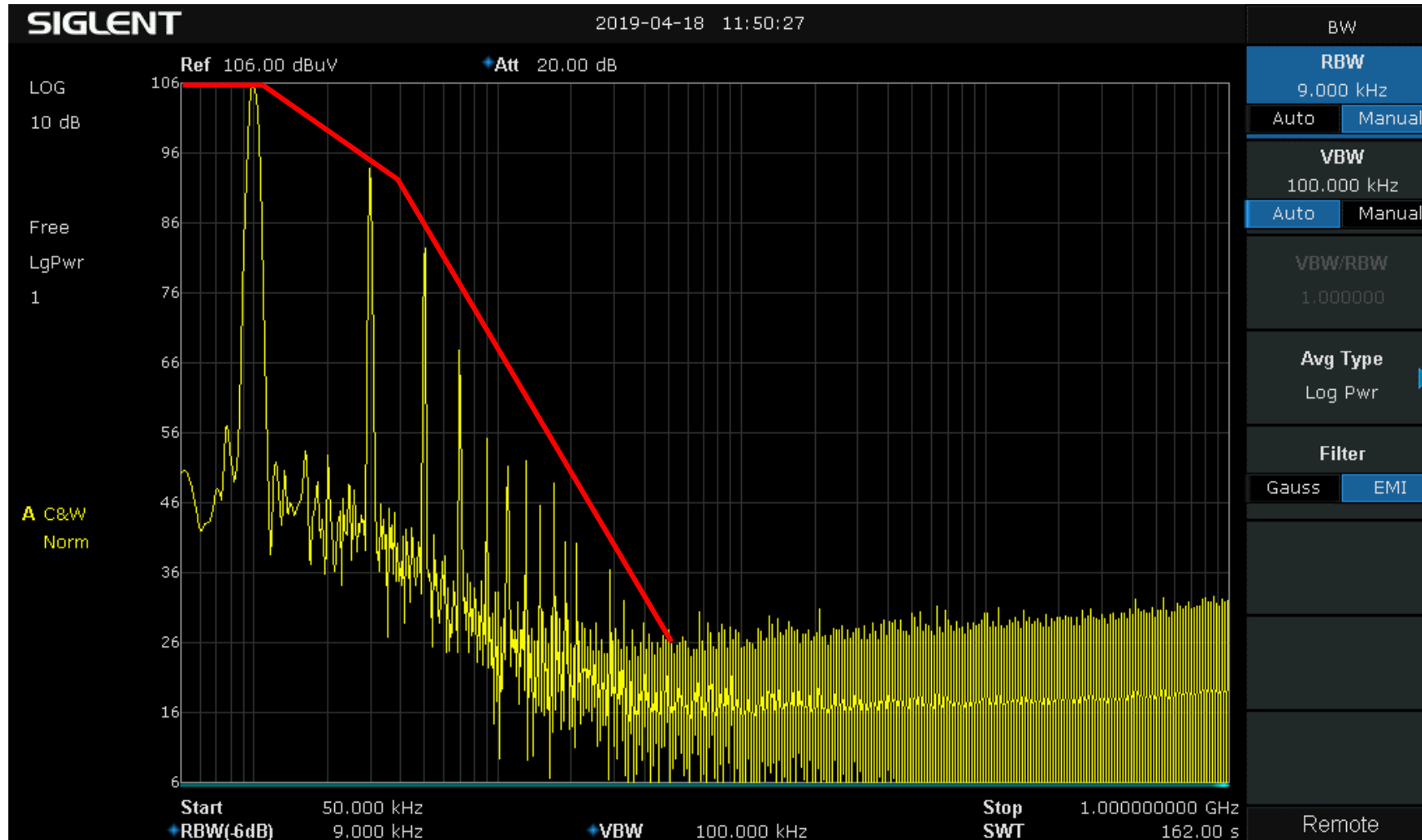
- 2nd Frequency point = $\frac{1}{\pi * RiseTime}$

1µs Rise Time => 318,3kHz

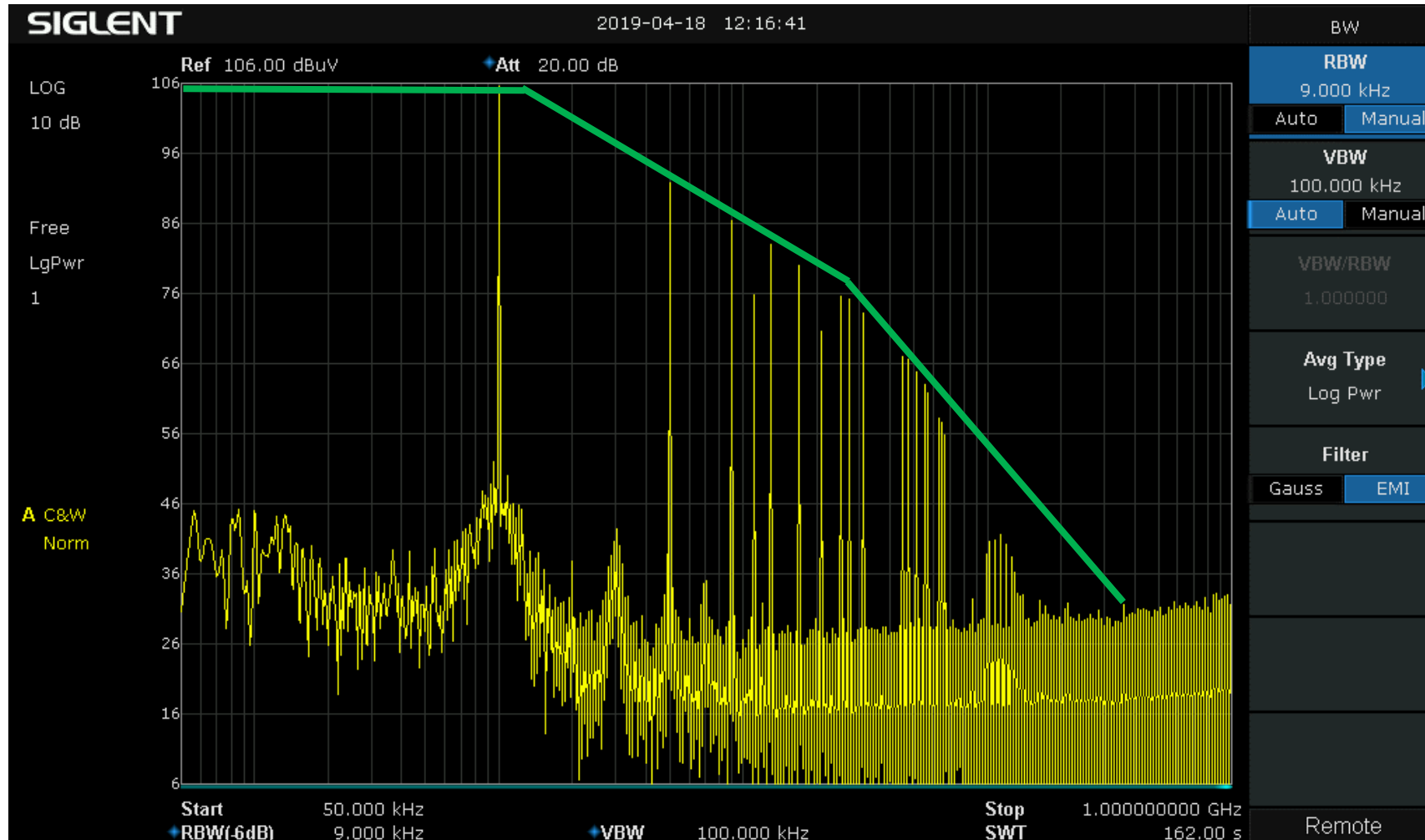
10ns Rise Time => 31,83MHz



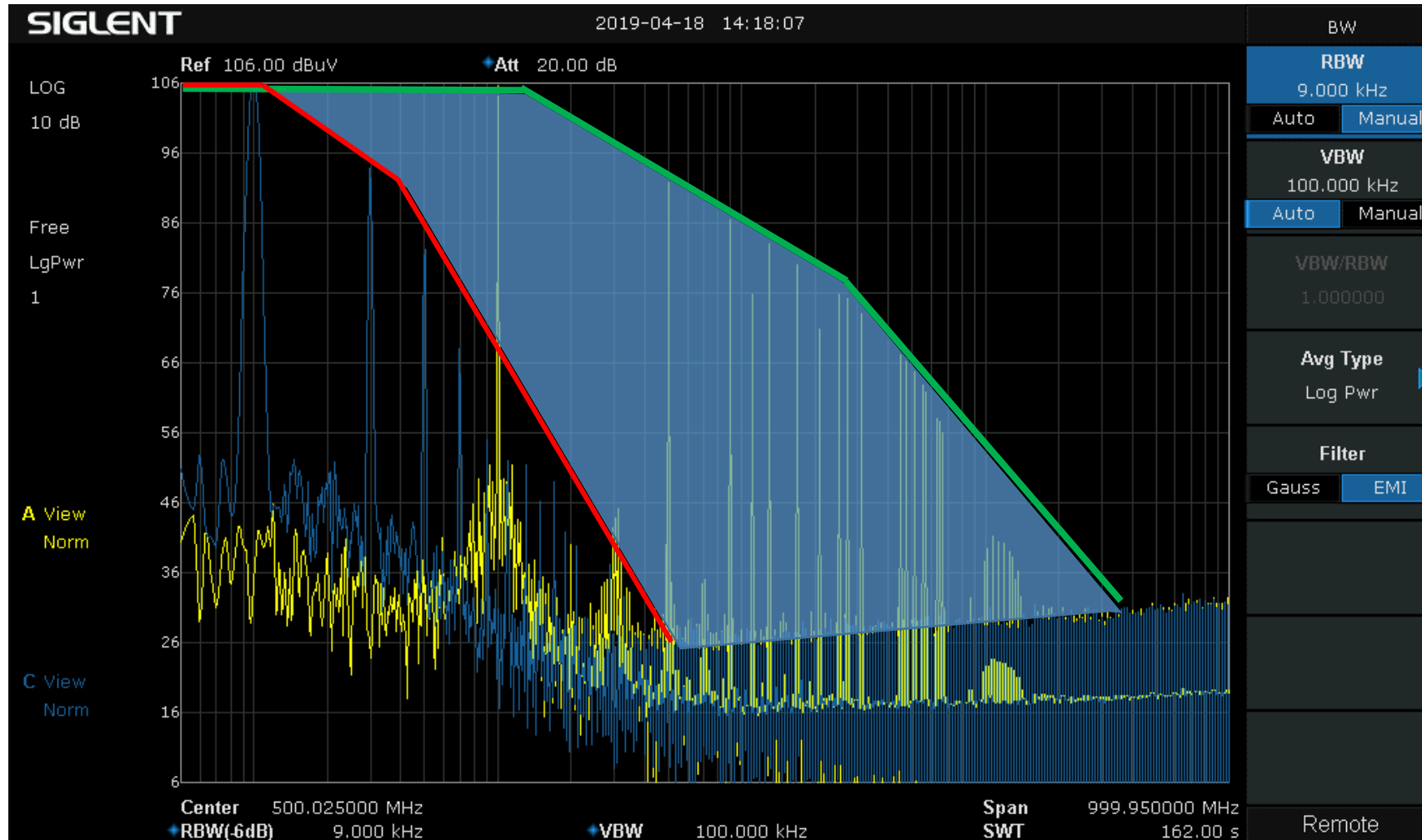
Faster Switching + steeper Edges



Faster Switching + steeper Edges



Faster Switching + steeper Edges



Design Considerations

- Critical loop as small as possible
- Grounding concept around Critical Loop
- Proper Grounding of Heat Sinks
- Uses Shielded Storage Inductivities
- Re-think the Filter concept (input / output)

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Who we are and What we offer?

**ELECTRONICS
& APPLICATIONS**
14T/M 16 MEI 2019 JAARBEURS UTRECHT



- Established in 2002
- Headquarter - Shenzhen, China
- Employees - over 300 incl. big R&D team
- ISO9001:2000 and ISO14001:2004
- CE certification on all products
- Professional integrated supply chain & production system
- Export to 70+ countries & regions

Time Domain Analysis



Signal Generation



Frequency Domain Analysis



General Purpose



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